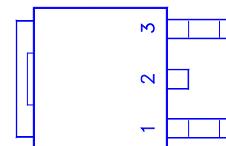
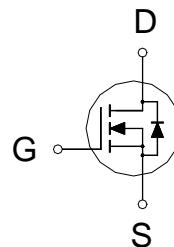


NIKO-SEM
**N-Channel Enhancement Mode
Field Effect Transistor**
PD632BA
TO-252
Halogen-Free & Lead-Free
PRODUCT SUMMARY

$V_{(BR)DSS}$	$R_{DS(ON)}$	I_D
30V	3.7mΩ	105A

**ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ Unless Otherwise Noted)**

PARAMETERS/TEST CONDITIONS		SYMBOL	LIMITS	UNITS
Drain-Source Voltage		V_{DS}	30	V
Gate-Source Voltage		V_{GS}	± 20	V
Continuous Drain Current ²	$T_C = 25^\circ\text{C}$	I_D	105	A
	$T_C = 100^\circ\text{C}$		66	
Pulsed Drain Current ¹		I_{DM}	200	A
Avalanche Current		I_{AS}	40	
Avalanche Energy	$L = 0.1\text{mH}$	E_{AS}	80	mJ
Power Dissipation	$T_C = 25^\circ\text{C}$	P_D	73	W
	$T_C = 100^\circ\text{C}$		29	
Junction & Storage Temperature Range		T_J, T_{stg}	-55 to 150	°C

THERMAL RESISTANCE RATINGS

THERMAL RESISTANCE	SYMBOL	TYPICAL	MAXIMUM	UNITS
Junction-to-Case	$R_{\theta JC}$		1.7	°C / W
Junction-to-Ambient	$R_{\theta JA}$		62.5	

¹Pulse width limited by maximum junction temperature.²Package limitation current is 55A**ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$, Unless Otherwise Noted)**

PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	
STATIC						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$	30			V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	1.3	1.7	2.3	
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0\text{V}, V_{GS} = \pm 20\text{V}$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 24\text{V}, V_{GS} = 0\text{V}$			1	μA
		$V_{DS} = 20\text{V}, V_{GS} = 0\text{V}, T_J = 125^\circ\text{C}$			10	
Drain-Source On-State Resistance ₁	$R_{DS(ON)}$	$V_{GS} = 4.5\text{V}, I_D = 30\text{A}$		3.4	4.8	$\text{m}\Omega$
		$V_{GS} = 10\text{V}, I_D = 40\text{A}$		2.8	3.7	

NIKO-SEM
**N-Channel Enhancement Mode
Field Effect Transistor**
PD632BA
TO-252
Halogen-Free & Lead-Free

Forward Transconductance ¹	g_{fs}	$V_{DS} = 5V, I_D = 40A$	70		S
DYNAMIC					
Input Capacitance	C_{iss}	$V_{GS} = 0V, V_{DS} = 15V, f = 1MHz$	2189		pF
Output Capacitance	C_{oss}		390		
Reverse Transfer Capacitance	C_{rss}		234		
Gate Resistance	R_g		1.4		
Total Gate Charge ²	$Q_{g(VGS=10V)}$	$V_{DS} = 15V, I_D = 20A$	44.2		nC
	$Q_{g(VGS=4.5V)}$		23.1		
Gate-Source Charge ²	Q_{gs}		5.6		
Gate-Drain Charge ²	Q_{gd}		10.7		
Turn-On Delay Time ²	$t_{d(on)}$	$V_{DS} = 15V$ $I_D \approx 20A, V_{GS} = 10V, R_{GEN} = 6\Omega$	25		nS
Rise Time ²	t_r		15		
Turn-Off Delay Time ²	$t_{d(off)}$		54		
Fall Time ²	t_f		17		
SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS ($T_J = 25^\circ C$)					
Continuous Current ³	I_S			105	A
Forward Voltage ¹	V_{SD}	$I_F = 40A, V_{GS} = 0V$		1	V
Reverse Recovery Time	t_{rr}	$I_F = 20A, dI_F/dt = 100A / \mu S$	25		nS
Reverse Recovery Charge	Q_{rr}		11		nC

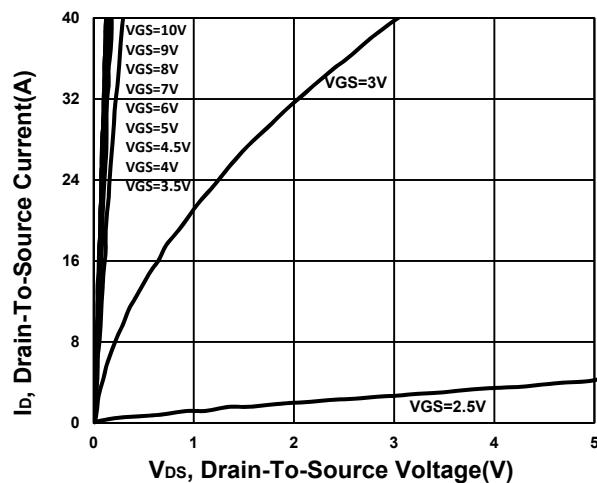
¹Pulse test : Pulse Width $\leq 300 \mu sec$, Duty Cycle $\leq 2\%$.²Independent of operating temperature.³Package limitation current is 55A

NIKO-SEM

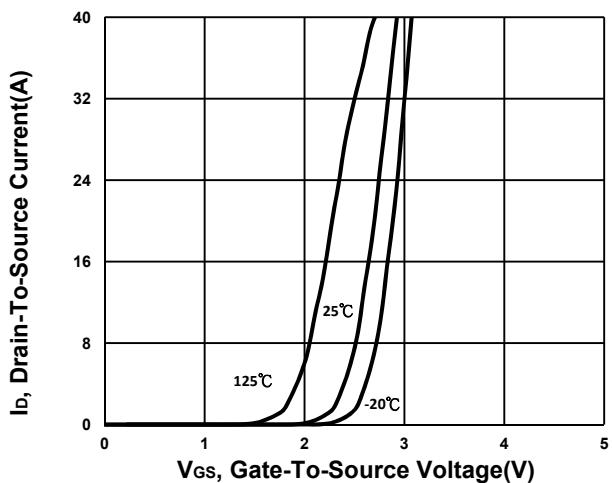
**N-Channel Enhancement Mode
Field Effect Transistor**

PD632BA
TO-252
Halogen-Free & Lead-Free

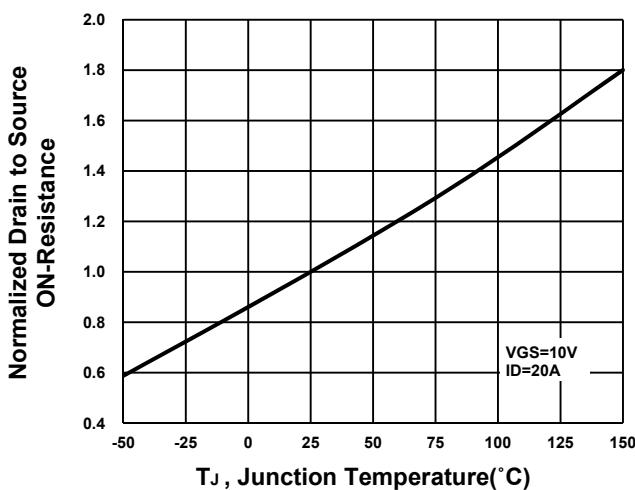
Output Characteristics



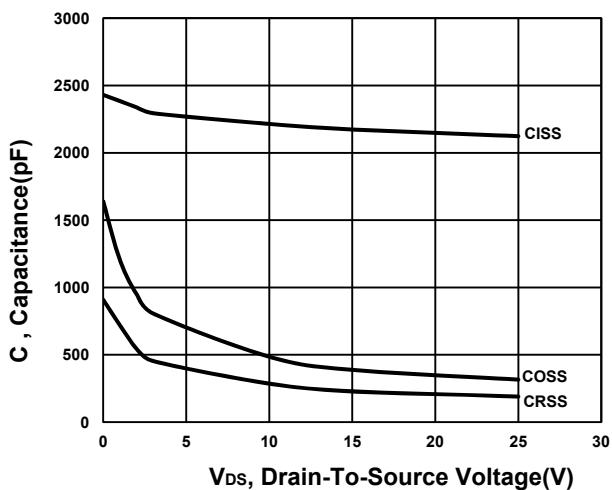
Transfer Characteristics



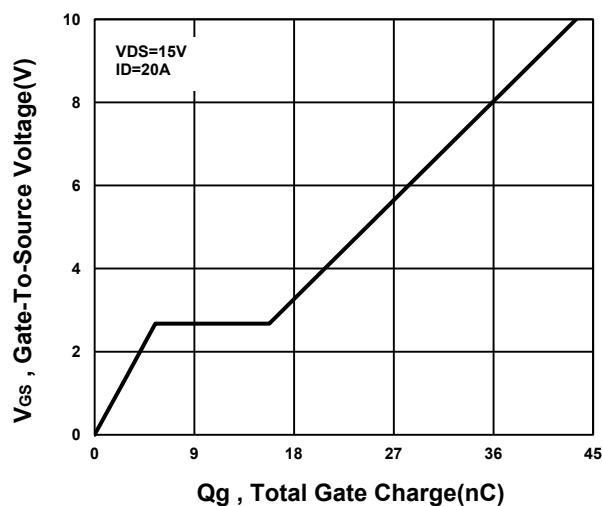
On-Resistance VS Temperature



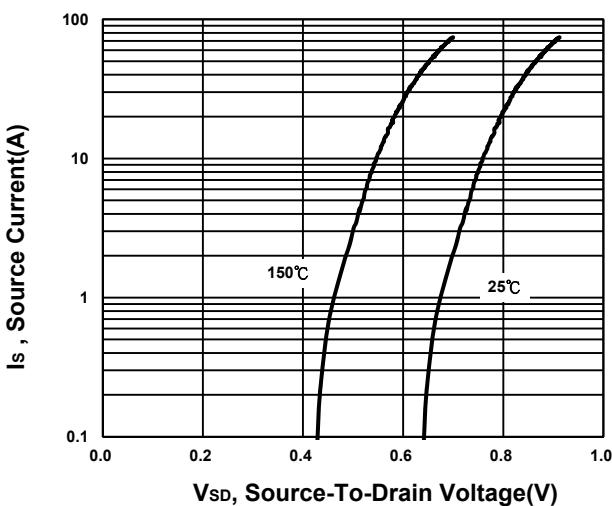
Capacitance Characteristic



Gate charge Characteristics



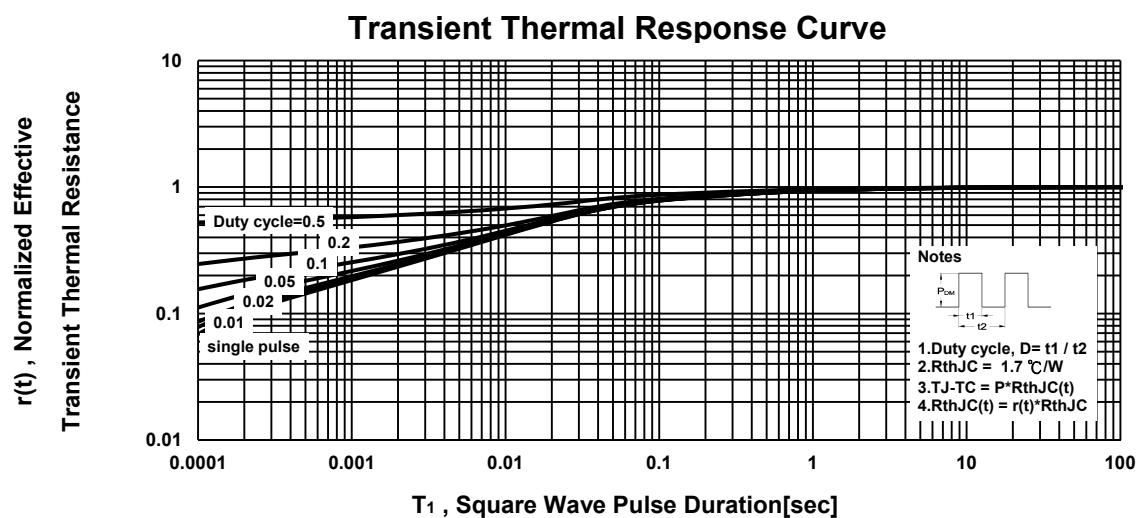
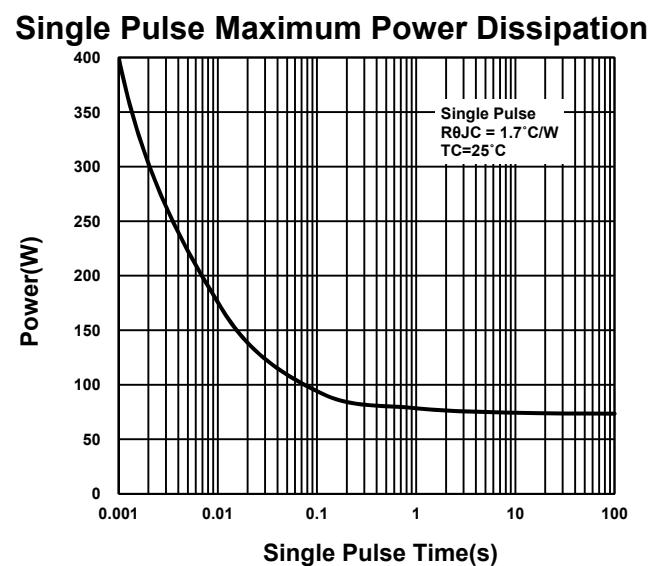
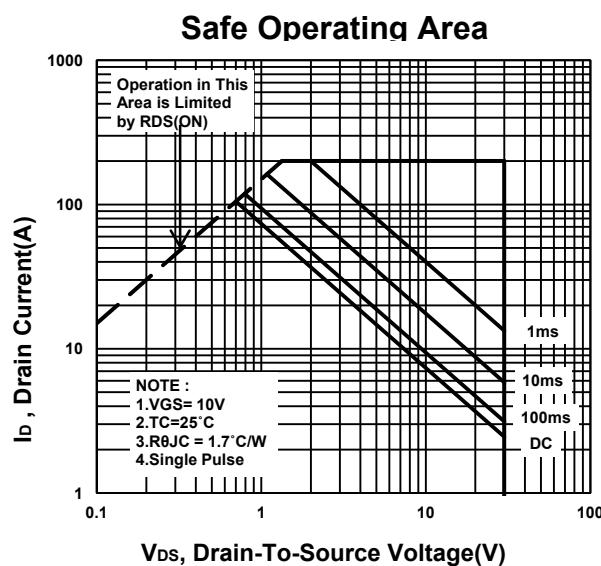
Source-Drain Diode Forward Voltage



NIKO-SEM

**N-Channel Enhancement Mode
Field Effect Transistor**

PD632BA
TO-252
Halogen-Free & Lead-Free



X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for MOSFET category:

Click to view products by NIKO manufacturer:

Other Similar products are found below :

[614233C](#) [648584F](#) [MCH3443-TL-E](#) [MCH6422-TL-E](#) [FDPF9N50NZ](#) [FW216A-TL-2W](#) [FW231A-TL-E](#) [APT5010JVR](#) [NTNS3A92PZT5G](#)
[IRF100S201](#) [JANTX2N5237](#) [2SK2464-TL-E](#) [2SK3818-DL-E](#) [FCA20N60_F109](#) [FDZ595PZ](#) [STD6600NT4G](#) [FSS804-TL-E](#) [2SJ277-DL-E](#)
[2SK1691-DL-E](#) [2SK2545\(Q,T\)](#) [D2294UK](#) [405094E](#) [423220D](#) [MCH6646-TL-E](#) [TPCC8103,L1Q\(CM](#) [367-8430-0972-503](#) [VN1206L](#)
[424134F](#) [026935X](#) [051075F](#) [SBVS138LT1G](#) [614234A](#) [715780A](#) [NTNS3166NZT5G](#) [751625C](#) [873612G](#) [IRF7380TRHR](#)
[IPS70R2K0CEAKMA1](#) [RJK60S3DPP-E0#T2](#) [RJK60S5DPK-M0#T0](#) [APT5010JVFR](#) [APT12031JFLL](#) [APT12040JVR](#) [DMN3404LQ-7](#)
[NTE6400](#) [JANTX2N6796U](#) [JANTX2N6784U](#) [JANTXV2N5416U4](#) [SQM110N05-06L-GE3](#) [SIHF35N60E-GE3](#)